

## J511 **Current Regulator Diode**



# Linear Systems replaces discontinued Siliconix J511

## The Linear Systems J511 is a ± 20% range current regulator

<ul> <li>The J511 is a ±20% range current regulator designed for demanding applications in test equipment and instrumentation.</li> <li>The J511 utilizes JFET techniques to produce a single two-leaded device which is extremely simple to operate.</li> <li>Two-Lead Plastic Package</li> <li>Guaranteed ±20% Tolerance</li> <li>Operation up to 50V</li> <li>Excellent Temperature Stability</li> <li>Simple Series Circuitry, No Separate Voltage Source</li> <li>Tight Guaranteed Circuit Performance</li> <li>Excellent Performance in Low-Voltage/Battery Circuits and High-Voltage Spike Protection</li> <li>High Circuit Stability vs. Temperature</li> </ul>	FEATURES				
	REPLACEMENT SOURCE FOR SILICONIX J511				
	WIDE CURRENT RANGE	4.70mA ± 20%			
	BIASING NOT REQUIRED	$V_{GS} = 0V$			
	ABSOLUTE MAXIMUM RATINGS <sup>1</sup>				
	@ 25 °C (unless otherwise stated)				
	Maximum Temperatures				
	Storage Temperature	-55 to 150°C			
	Junction Operating Temperature	-55 to 135°C			
	Maximum Power Dissipation				
	Continuous Power Dissipation @125°C	360mW			
J511 Applications:	Maximum Currents				
Constant-Current Supply	Forward Current	20mA			
	Reverse Current	50mA			
Current-Limiting     Timing Circuits	Maximum Voltages				
	Peak Operating Voltage	P <sub>OV</sub> = 50V			

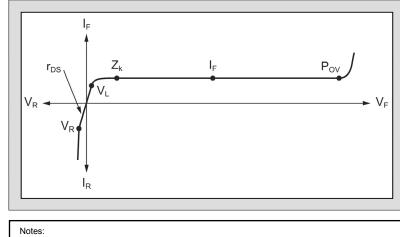
### ELECTRICAL CHARACTERISTICS @ 25 °C (unless otherwise stated)

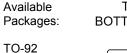
SYMBOL	CHARACTERISTIC	MIN	TYP	MAX	UNITS	CONDITIONS
Pov	Peak Operating Voltage <sup>2</sup>	50			V	$I_F = 1.1I_{F(max)}$
V <sub>R</sub>	Reverse Voltage		0.8		V	I <sub>R</sub> = 1mA
C <sub>F</sub>	Forward Capacitance		2.2		рF	V <sub>F</sub> = 25V, <i>f</i> = 1MHz

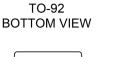
### SPECIFIC ELECTRICAL CHARACTERISTICS @ 25 °C (unless otherwise stated)

PART	Fo	orward Currer I <sub>F</sub>	nt <sup>3</sup>	Dynamic Impedance <sup>4</sup> Z <sub>d</sub>		Knee Impedance Z <sub>k</sub>	Limiting Voltage <sup>5</sup> V∟	
		V <sub>F</sub> = 25V		V <sub>F</sub> = 25V		V <sub>F</sub> = 6V	$I_F = 0.8I_{F(min)}$	
	MIN	NOM	MAX	MIN	TYP	TYP	TYP	MAX
J511	3.800	4.70	5.600	0.12	0.3	0.05	4.2	2.1

#### V-I CHARACTERISTICS CURRENT REGULATING DIODE







Bare Die.

Κ

Please contact Micross for full package and die dimensions

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1. Absolute maximum ratings are limiting values above which serviceability may be impaired. 2. Pulsed, t = 2ms. Maximum V<sub>F</sub> where IF <  $1.1_{\rm IF}$ (max).

2. Fulsed, t = 2ms. Continuous currents may vary. 3. Pulsed, t = 2ms. Continuous impedances may vary. 4. Pulsed, t = 2ms. Continuous impedances may vary. 5. Min V<sub>F</sub> required to ensure  $I_F = 0.8_{IF}$ (min).

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